

10V Drive Nch MOSFET

R5013ANJ

●Structure

Silicon N-channel MOSFET

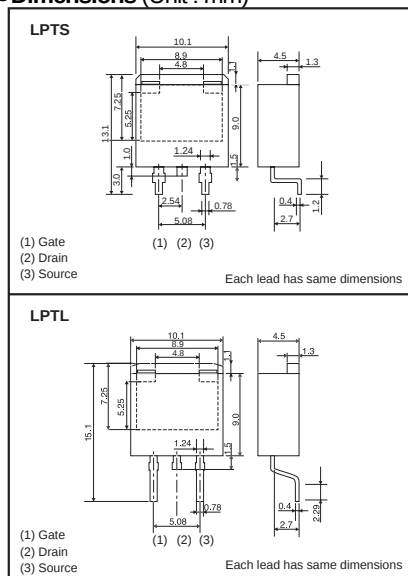
●Features

- 1) Low on-resistance.
- 2) Fast switching speed.
- 3) Gate-source voltage (V_{GS}) guaranteed to be $\pm 30V$.
- 4) Drive circuits can be simple.
- 5) Parallel use is easy.

●Applications

Switching

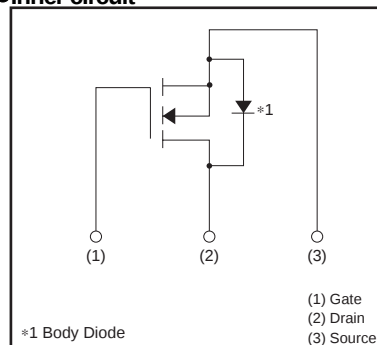
●Dimensions (Unit : mm)



●Packaging specifications

Type	Package	Taping	
	Code	LPTS	TL
		LPTL	TLL
	Basic ordering unit (pieces)		1000

●Inner circuit



●Absolute maximum ratings ($T_a=25^\circ C$)

Parameter		Symbol	Limits	Unit
Drain-source voltage		V_{DS}	500	V
Gate-source voltage		V_{GS}	± 30	V
Drain current	Continuous	I_D *3	± 13	A
	Pulsed	I_{DP} *1	± 52	A
Source current (Body Diode)	Continuous	I_S *3	13	A
	Pulsed	I_{SP} *1	52	A
Avalanche current		I_{AS} *2	6.5	A
Avalanche energy		E_{AS} *2	11.3	mJ
Total power dissipation ($T_c=25^\circ C$)		P_D	100	W
Channel temperature		T_{ch}	150	$^\circ C$
Range of storage temperature		T_{stg}	-55 to +150	$^\circ C$

*1 $P_w \leq 10 \mu s$, Duty cycle $\leq 1\%$

*2 $L = 500 \mu H$, $V_{DD} = 50V$, $R_G = 25 \Omega$, Starting, $T_{ch} = 25^\circ C$

*3 Limited only by maximum temperature allowed

●Thermal resistance

Parameter	Symbol	Limits	Unit
Channel to case	$R_{th(ch-c)}$	1.25	$^\circ C/W$

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Gate-source leakage	I_{GSS}	—	—	± 100	nA	$V_{GS}=\pm 30V$, $V_{DS}=0V$
Drain-source breakdown voltage	$V_{(BR)DSS}$	500	—	—	V	$I_D=1mA$, $V_{GS}=0V$
Zero gate voltage drain current	I_{DSS}	—	—	100	μA	$V_{DS}=500V$, $V_{GS}=0V$
Gate threshold voltage	$V_{GS(th)}$	2.5	—	4.5	V	$V_{DS}=10V$, $I_D=1mA$
Static drain-source on-state resistance	$R_{DS(on)}^*$	—	0.29	0.38	Ω	$I_D=6.5A$, $V_{GS}=10V$
Forward transfer admittance	$ Y_{fs} $	4.0	—	—	S	$V_{DS}=10V$, $I_D=6.5A$
Input capacitance	C_{iss}	—	1300	—	pF	$V_{DS}=25V$
Output capacitance	C_{oss}	—	500	—	pF	$V_{GS}=0V$
Reverse transfer capacitance	C_{rss}	—	40	—	pF	$f=1MHz$
Turn-on delay time	$t_{d(on)}^*$	—	30	—	ns	$V_{DD}\approx 250V$, $I_D=6.5A$
Rise time	t_r^*	—	32	—	ns	$V_{GS}=10V$
Turn-off delay time	$t_{d(off)}^*$	—	90	—	ns	$R_L=38.5\Omega$
Fall time	t_f^*	—	30	—	ns	$R_G=10\Omega$
Total gate charge	Q_g^*	—	35	—	nC	$V_{DD}\approx 250V$
Gate-source charge	Q_{gs}^*	—	8	—	nC	$I_D=13A$
Gate-drain charge	Q_{gd}^*	—	15	—	nC	$V_{GS}=10V$
						$R_L=19.2\Omega$ / $R_G=10\Omega$

* Pulsed

●Body diode characteristics (Source-drain) (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward voltage	V_{SD}^*	—	—	1.5	V	$I_S=13A$, $V_{GS}=0V$

* Pulsed

●Electrical characteristic curves

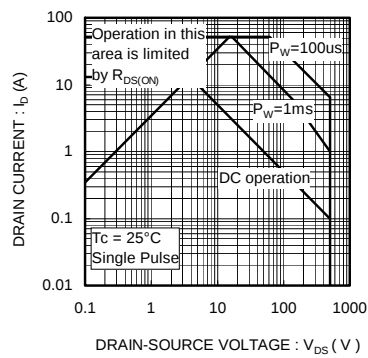


Fig.1 Maximum Safe Operating Area

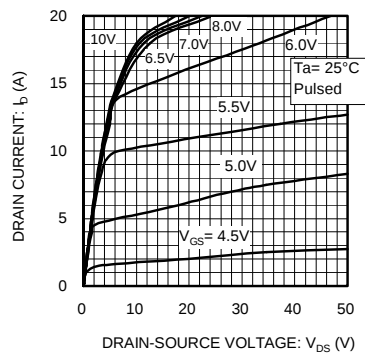


Fig.2 Typical Output Characteristics(I)

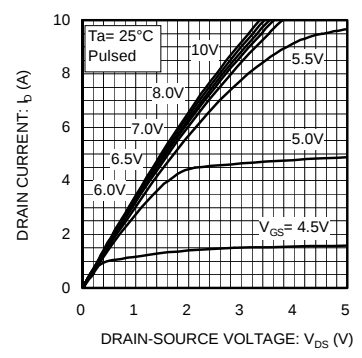


Fig.3 Typical Output Characteristics(II)

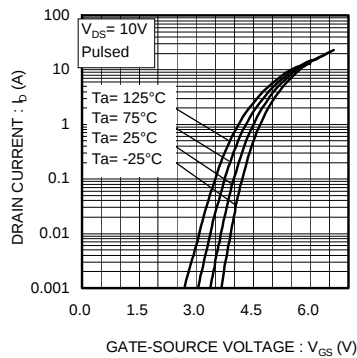


Fig.4 Typical Transfer Characteristics

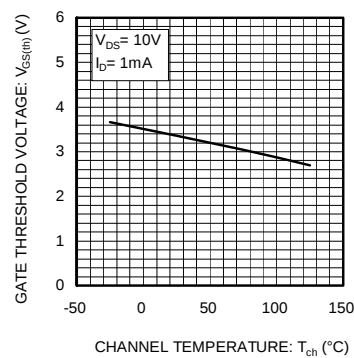


Fig.5 Gate Threshold Voltage vs. Channel Temperature

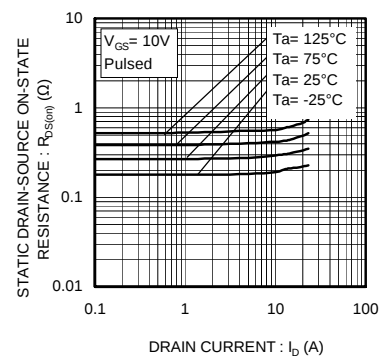


Fig.6 Static Drain-Source On-State Resistance vs. Drain Current

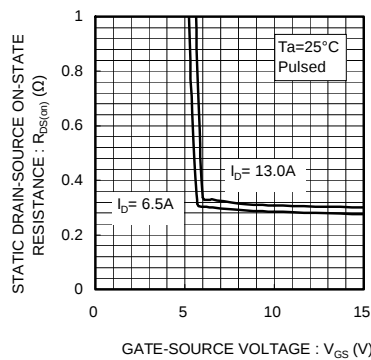


Fig.7 Static Drain-Source On-State Resistance vs. Gate Source

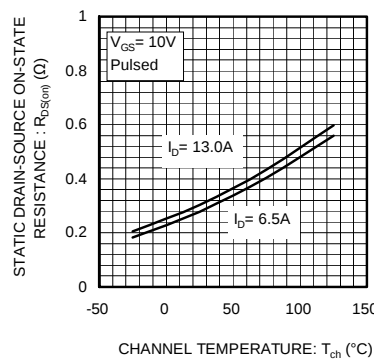


Fig.8 Static Drain-Source On-State Resistance vs. Channel

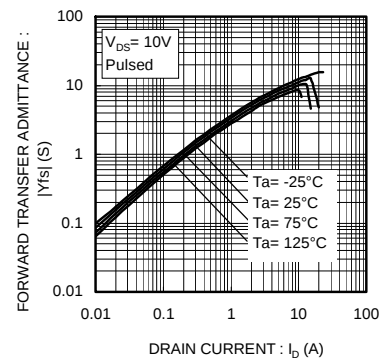


Fig.9 Forward Transfer Admittance vs. Drain Current

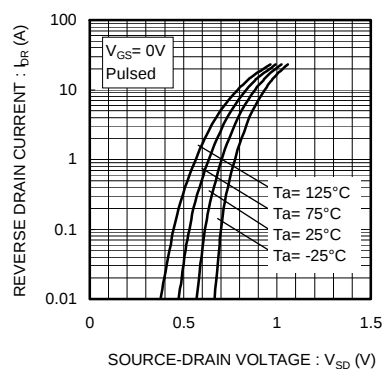


Fig.10 Reverse Drain Current vs. Source-Drain Voltage

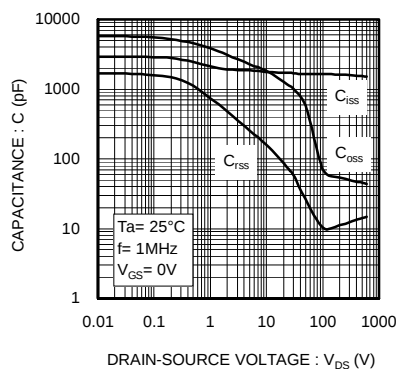


Fig.11 Typical Capacitance vs. Drain-Source Voltage

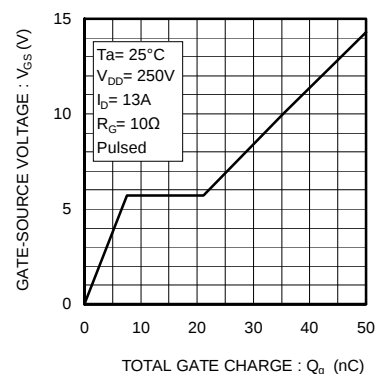


Fig.12 Dynamic Input Characteristics

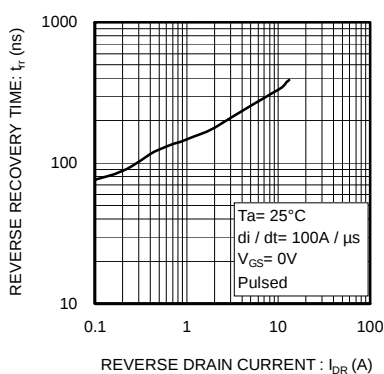


Fig.13 Reverse Recovery Time vs. Reverse Drain Current

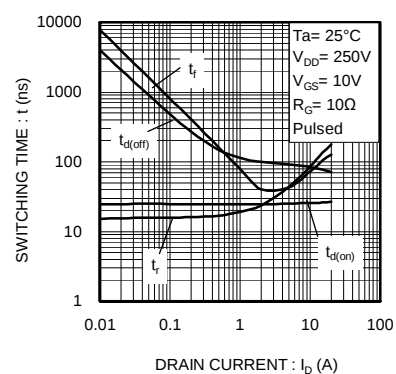


Fig.14 Switching Characteristics

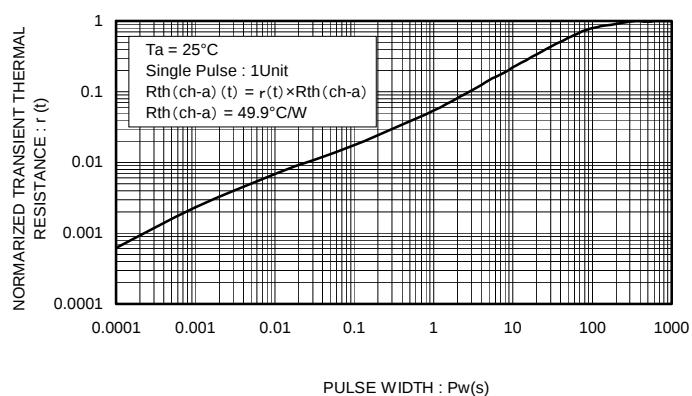


Fig.15 Normalized Transient Thermal Resistance vs. Pulse Width

●Switching characteristics measurement circuit

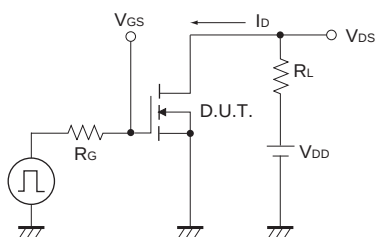


Fig.1-1 Switching time measurement circuit

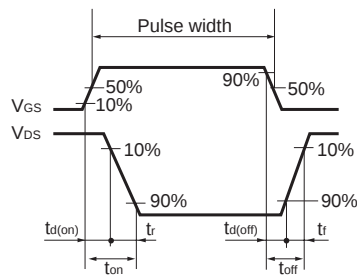


Fig.1-2 Switching waveforms

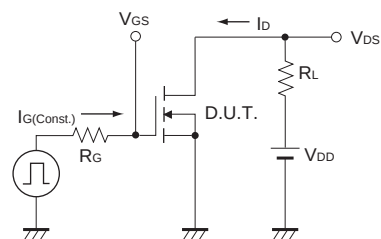


Fig.2-1 Gate charge measurement circuit

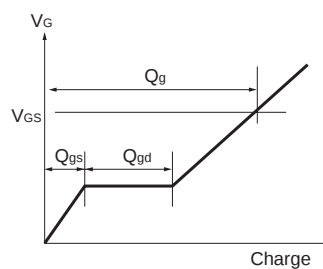


Fig.2-2 Gate charge waveform

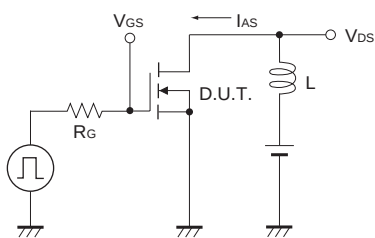


Fig.3-1 Avalanche Measurement circuit

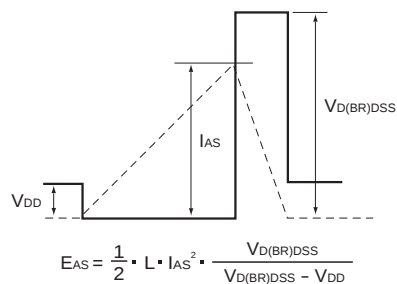


Fig.3-2 Avalanche waveform

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